

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	27923	single near5 (crystal crystalline) near5 silicon	US-PGPU B; USPAT; USOCR	OR	ON	2005/04/04 17:55
L2	778	mono near5 (crystal crystalline) near5 silicon	US-PGPU B; USPAT; USOCR	OR	ON	2005/04/04 17:55
L3	28569	1 2	US-PGPU B; USPAT; USOCR	OR	ON	2005/04/04 17:46
L4	18401	3 and (dop\$3 implant\$3)	US-PGPU B; USPAT; USOCR	OR	ON	2005/04/04 17:55
L5	14251	4 and (anneal\$3 heat\$3)	US-PGPU B; USPAT; USOCR	OR	ON	2005/04/04 17:46
L6	7203	5 and (inert nitrogen "N.sub." (non near5 dopant))	US-PGPU B; USPAT; USOCR	OR	ON	2005/04/04 17:55
L7	3570	6 and (insulat\$3 dielectric)	US-PGPU B; USPAT; USOCR	OR	ON	2005/04/04 17:56
L8	0	(implant\$3 dop\$3) near100 ((mono single) near5 (crystal crystalline) near5 silicon) near100 (inert nitrogen "N.sub.2") near100 (heat\$3 anneal\$3) near100 diffus\$3 near100 (insulat\$3 dielectric)	US-PGPU B; USPAT; USOCR	OR	ON	2005/04/04 17:52
L9	21	(implant\$3 dop\$3) same((mono single) near5 (crystal crystalline) near5 silicon) same (inert nitrogen "N.sub.2") same (heat\$3 anneal\$3) same diffus\$3 same (insulat\$3 dielectric)	US-PGPU B; USPAT; USOCR	OR	ON	2005/04/04 17:52
L10	9	7 and 9	US-PGPU B; USPAT; USOCR	OR	ON	2005/04/04 17:52
L11	16430	single near5 (crystal crystalline) near5 silicon	EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/04/04 17:55
L12	455	mono near5 (crystal crystalline) near5 silicon	EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/04/04 17:55

L13	16860	11 12	EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/04/04 17:55
L14	2431	13 and (dop\$3 implant\$3)	EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/04/04 17:55
L15	334	14 and (inert nitrogen "N.sub. " (non near5 dopant))	EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/04/04 17:56
L16	19	15 and (insualt\$3 dielectric)	EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/04/04 17:56